## MCH6661

# N-Channel Power MOSFET 30V, 1.8A, 188mΩ, Dual MCPH6



#### **Features**

- ON-resistance Nch :  $RDS(on)1=145m\Omega$  (typ.)
- 4V drive
- · Halogen free compliance

#### **Specifications**

#### **Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Value	Unit
Drain to Source Voltage	VDSS		30	V
Gate to Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		1.8	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	7.2	А
Power Dissipation	PD	When mounted on ceramic substrate (900mm²×0.8mm) 1unit	0.8	W
Junction Temperature	Tj		150	°C
Storage Temperature Purposes,	Tstg		-55 to +150	°C
Lead Temperature for Soldering Purposes, 3mm from Case for 10 Seconds	TL		260	°C

This product is designed to "ESD immunity < 200V\*", so please take care when handling.

#### **Thermal Resistance Ratings**

Parameter	Symbol	Value	Unit	
Junction to Ambient	R <sub>0</sub> JA	156.3	°C/W	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

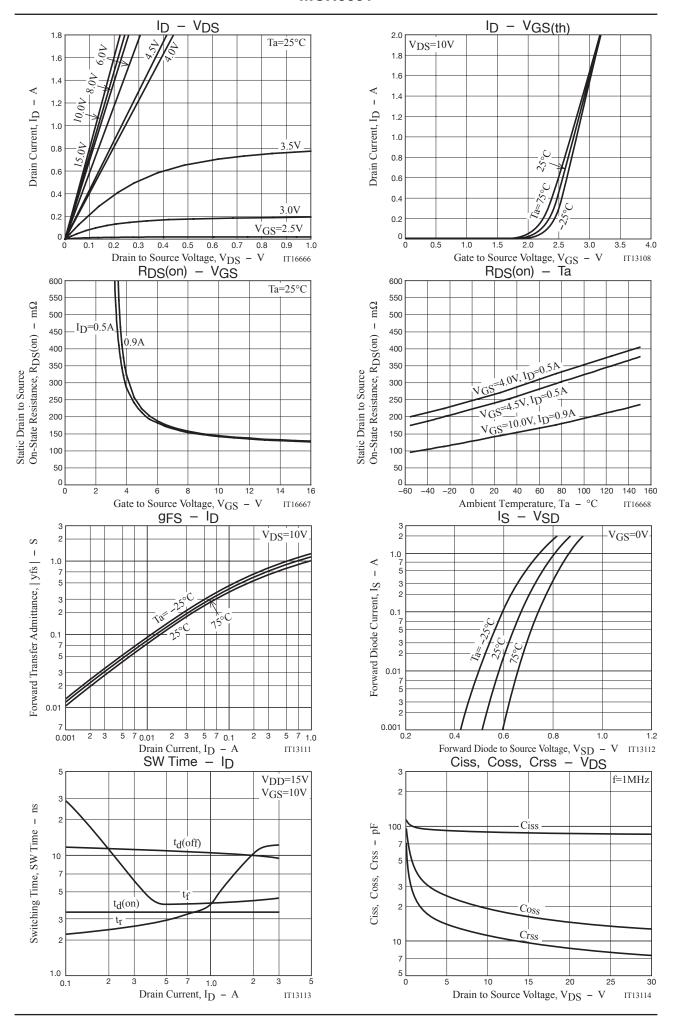
#### Electrical Characteristics at Ta=25°C

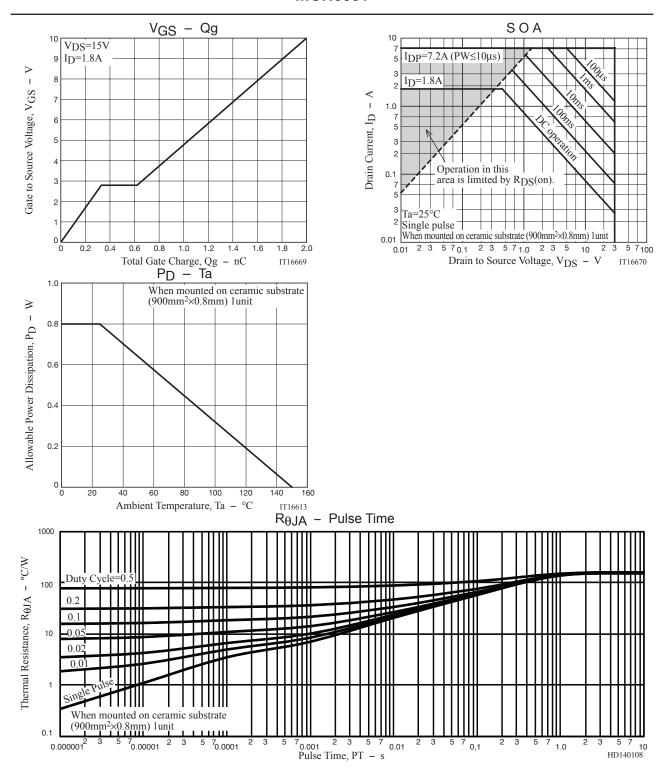
Parameter	Symbol	Conditions	Value			Unit	
Farameter	Symbol	Conditions	min	typ	max	UIIIL	
Drain to Source Breakdown Voltage	kdown Voltage V <sub>(BR)DSS</sub> I <sub>D</sub> =1mA, V <sub>GS</sub> =0V		30			V	
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V			1	μΑ	
Gate to Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μΑ	
Gate Threshold Voltage	VGS(th)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V	
Forward Transconductance	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =0.9A		1.1		S	
	R <sub>DS</sub> (on)1	I <sub>D</sub> =0.9A, V <sub>G</sub> S=10V		145	188	mΩ	
Static Drain to Source On-State Resistance	R <sub>DS</sub> (on)2	I <sub>D</sub> =0.5A, V <sub>GS</sub> =4.5V		245	343	mΩ	
	RDS(on)3	ID=0.5A, VGS=4V		270	378	mΩ	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		88		рF	
Output Capacitance	Coss			19		рF	
Reverse Transfer Capacitance	Crss			11		рF	
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		3.4		ns	
Rise Time	tr			3.6		ns	
Turn-OFF Delay Time	t <sub>d</sub> (off)			10.5		ns	
Fall Time	tf			4.0		ns	
Total Gate Charge	Qg			2.0		nC	
Gate to Source Charge	Qgs	V <sub>DS</sub> =15V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.8A		0.33		nC	
Gate to Drain "Miller" Charge	Qgd			0.29		nC	
Forward Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> =1.8A, V <sub>GS</sub> =0V		0.86	1.2	V	

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

<sup>\*</sup> Machine Model





#### **Package Dimensions**

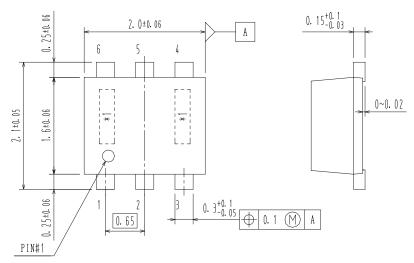
MCH6661-TL-W

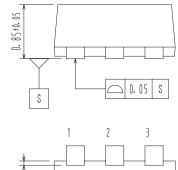
#### SC-88FL / MCPH6

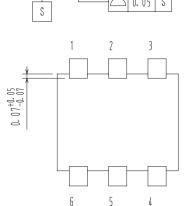
CASE 419AS ISSUE O

unit: mm

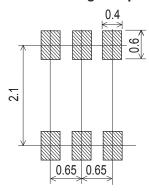
- 1:Source1
- 2:Gate1
- 3:Drain2
- 4:Source2
- 5:Gate2
- 6:Drain1







## Recommended Soldering Footprint

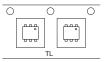


\*1:Lot indication

#### **Ordering & Package Information**

Device	Package	Shipping	note
MCH6661-TL-W	MCPH6, SC-88,SOT-363	3,000 pcs. / reel	Pb-Free and Halogen Free

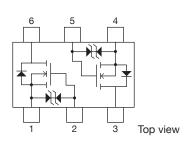
#### Packing Type:TL



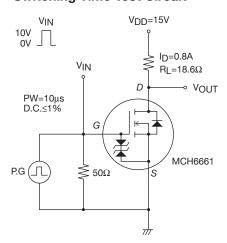


Marking

#### **Electrical Connection**



#### **Switching Time Test Circuit**



#### MCH6661

Note on usage: Since the MCH6661 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/A

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

614233C 648584F IRFD120 JANTX2N5237 FCA20N60\_F109 FDZ595PZ 2SK2545(Q,T) 405094E 423220D TPCC8103,L1Q(CM MIC4420CM-TR VN1206L SBVS138LT1G 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C BUK954R8-60E NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE222 NTE2384 NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956 NTE2956 NTE2911 DMN2080UCB4-7 TK10A80W,S4X(S SSM6P69NU,LF DMP22D4UFO-7B